HEF4044B

Quad R/S latch with 3-state outputs Rev. 10 — 18 November 2011

Product data sheet

1. **General description**

The HEF4044B is a quad R/S latch with 3-state outputs, with a common output enable input (OE). Each latch has an active LOW set input (1S to 4S), an active LOW reset input (1R to 4R) and an active HIGH 3-state output (1Q to 4Q).

When OE is HIGH, the latch output (nQ) is determined by the $n\overline{R}$ and $n\overline{S}$ inputs as shown in Table 3. When OE is LOW, the latch outputs are in the high impedance OFF-state. OE does not affect the state of the latch. The high impedance off-state feature allows common bussing of the outputs.

It operates over a recommended V_{DD} power supply range of 3 V to 15 V referenced to V_{SS} (usually ground). Unused inputs must be connected to V_{DD}, V_{SS}, or another input.

2. **Features and benefits**

- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Specified from -40 °C to +85 °C
- Complies with JEDEC standard JESD 13-B

3. **Applications**

Four-bit storage with output enable

Ordering information

Table 1. **Ordering information**

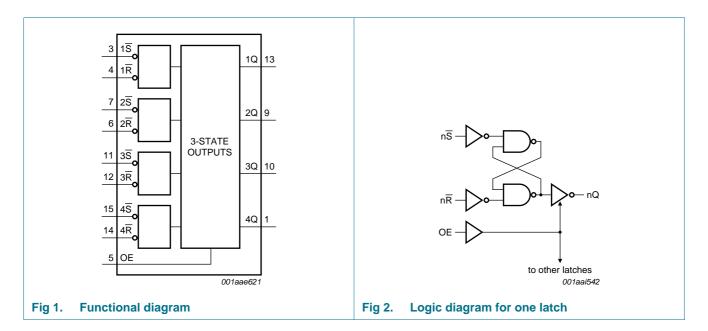
All types operate from -40 °C to +85 °C.

Type number	Package											
	Name	Description	Version									
HEF4044BP	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4									
HEF4044BT	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1									



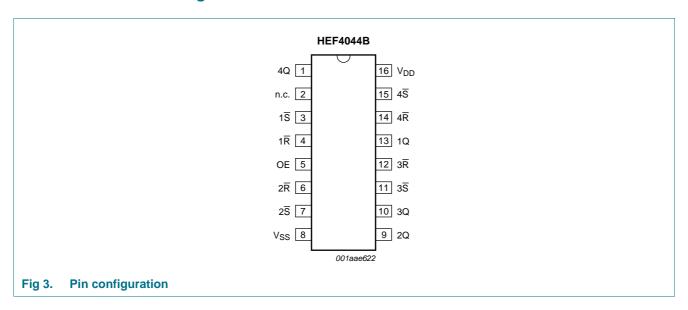
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5. Functional diagram



6. Pinning information

6.1 Pinning



Quad R/S latch with 3-state outputs

6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
n.c.	2	not connected
$1\overline{S}$ to $4\overline{S}$	3, 7, 11, 15	set input (active LOW)
$1\overline{R}$ to $4\overline{R}$	4, 6, 12, 14	reset input (active LOW)
OE	5	common output enable input
V_{SS}	8	ground supply voltage
1Q to 4Q	13, 9, 10, 1	3-state buffered latch output
V_{DD}	16	supply voltage

7. Functional description

Table 3. Function table[1]

Input OE	nput						
OE	nS	nR	nQ				
L	X	X	Z				
Н	L	Н	Н				
Н	X	L	L				
Н	Н	Н	latched				

^[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high impedance state.

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DD}	supply voltage		-0.5	+18	V
I _{IK}	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{DD} + 0.5 \text{ V}$	-	±10	mA
VI	input voltage		-0.5	$V_{DD} + 0.5$	V
l _{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{DD} + 0.5 \text{ V}$	-	±10	mA
I _{I/O}	input/output current		-	±10	mA
I _{DD}	supply current		-	50	mA
T _{stg}	storage temperature		-65	+150	°C
T _{amb}	ambient temperature		-40	+85	°C
P _{tot}	total power dissipation	T_{amb} –40 °C to +85 °C			
		DIP16 package	<u>[1]</u> -	750	mW
		SO16 package	[2] -	500	mW
		per output	-	100	mW

^[1] For DIP16 package: P_{tot} derates linearly with 12 mW/K above 70 °C.

^[2] For SO16 package: P_{tot} derates linearly with 8 mW/K above 70 °C.

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9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DD}	supply voltage		3	-	15	V
VI	input voltage		0	-	V_{DD}	V
T _{amb}	ambient temperature	in free air	-40	-	+85	°C
Δt/ΔV	input transition rise and fall rate	$V_{DD} = 5 V$	-	-	3.75	μs/V
		V _{DD} = 10 V	-	-	0.5	μs/V
		V _{DD} = 15 V	-	-	0.08	μs/V

10. Static characteristics

Table 6. Static characteristics

 $V_{SS} = 0$ V; $V_I = V_{SS}$ or V_{DD} unless otherwise specified.

Symbol	Parameter	Conditions	V_{DD}	T _{amb} =	–40 °C	T _{amb} =	25 °C	T _{amb} = 85 °C		Unit
				Min	Max	Min	Max	Min	Max	
V_{IH}	HIGH-level input voltage	$ I_{O} < 1 \mu A$	5 V	3.5	-	3.5	-	3.5	-	V
			10 V	7.0	-	7.0	-	7.0	-	V
			15 V	11.0	-	11.0	-	11.0	-	V
V _{IL}	LOW-level input voltage	$ I_{O} < 1 \mu A$	5 V	-	1.5	-	1.5	-	1.5	V
			10 V	-	3.0	-	3.0	-	3.0	V
			15 V	-	4.0	-	4.0	-	4.0	V
V _{OH}	HIGH-level output voltage	$ I_{O} < 1 \mu A$	5 V	4.95	-	4.95	-	4.95	-	V
			10 V	9.95	-	9.95	-	9.95	-	V
			15 V	14.95	-	14.95	-	14.95	-	V
V _{OL} I	LOW-level output voltage	$ I_{O} < 1 \mu A$	5 V	-	0.05	-	0.05	-	0.05	V
			10 V	-	0.05	-	0.05	-	0.05	V
			15 V	-	0.05	-	0.05	-	0.05	V
I _{OH}	HIGH-level output current	$V_0 = 2.5 \text{ V}$	5 V	-	-1.7	-	-1.4	-	-1.1	mΑ
		$V_0 = 4.6 \text{ V}$	5 V	-	-0.52	-	-0.44	-	-0.36	mΑ
		$V_0 = 9.5 \text{ V}$	10 V	-	-1.3	-	-1.1	-	-0.9	mΑ
		V _O = 13.5 V	15 V	-	-3.6	-	-3.0	-	-2.4	mΑ
I _{OL}	LOW-level output current	$V_0 = 0.4 \text{ V}$	5 V	0.52	-	0.44	-	0.36	-	mΑ
		$V_0 = 0.5 \text{ V}$	10 V	1.3	-	1.1	-	0.9	-	mΑ
		V _O = 1.5 V	15 V	3.6	-	3.0	-	2.4	-	mΑ
II	input leakage current		15 V	-	±0.3	-	±0.3	-	±1.0	μΑ
l _{OZ}	OFF-state output current	nQ output HIGH; returned to V _{DD}	15 V	-	1.6	-	1.6	-	12.0	μΑ
		nQ output LOW; returned to V _{SS}	15 V	-	1.6	-	1.6	-	12.0	μΑ

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 Table 6.
 Static characteristics ...continued

 $V_{SS} = 0 \ V$; $V_I = V_{SS}$ or V_{DD} unless otherwise specified.

Symbol	Parameter	Conditions	V_{DD}	T _{amb} =	T _{amb} = -40 °C		T _{amb} = 25 °C		T _{amb} = 85 °C	
				Min	Max	Min	Max	Min	Max	
I_{DD}	supply current	I _O = 0 A	5 V	-	20	-	20	-	150	μΑ
			10 V	-	40	-	40	-	300	μΑ
			15 V	-	80	-	80	-	600	μΑ
Cı	input capacitance			-	-	-	7.5	-	-	pF

11. Dynamic characteristics

Table 7. Dynamic characteristics

 $V_{SS} = 0 \text{ V}$; $T_{amb} = 25 \text{ °C}$; for test circuit see <u>Figure 6</u>; unless otherwise specified.

Symbol	Parameter	Conditions	V_{DD}	Extrapolation formula	Min	Тур	Max	Unit
t _{PHL}	HIGH to LOW	$n\overline{R}$ to nQ ; see	5 V	[1] 63 ns + (0.55 ns/pF)C _L	-	90	185	ns
	propagation delay	Figure 4	10 V	29 ns + (0.23 ns/pF)C _L	-	40	80	ns
			15 V	22 ns + (0.16 ns/pF)C _L	-	30	60	ns
t _{PLH}	LOW to HIGH	$n\overline{S}$ to nQ ;	5 V	[1] 63 ns + (0.55 ns/pF)C _L	-	90	180	ns
	propagation delay	see Figure 4	10 V	29 ns + (0.23 ns/pF)C _L	-	40	80	ns
			15 V	22 ns + (0.16 ns/pF)C _L	-	30	60	ns
t _t	transition time	see Figure 4	5 V	10 ns + (1.00 ns/pF)C _L	-	60	120	ns
			10 V	9 ns + (0.42 ns/pF)C _L	-	30	60	ns
			15 V	6 ns + (0.28 ns/pF)C _L	-	20	40	ns
t _{PHZ}	HIGH to OFF-state	$OE \rightarrow nQ;$	5 V		-	50	100	ns
	propagation delay	see <u>Figure 5</u>	10 V		-	30	60	ns
			15 V		-	25	50	ns
t _{PLZ}	LOW to OFF-state	OE → nQ; see <u>Figure 5</u>	5 V		-	30	60	ns
	propagation delay		10 V		-	25	45	ns
			15 V		-	20	40	ns
t _{PZH}	OFF-state to HIGH	OE \rightarrow nQ; see <u>Figure 5</u>	5 V		-	50	100	ns
	propagation delay		10 V		-	25	50	ns
			15 V		-	20	40	ns
t _{PZL}	OFF-state to LOW	$OE \rightarrow nQ;$	5 V		-	50	95	ns
	propagation delay	see <u>Figure 5</u>	10 V		-	25	45	ns
			15 V		-	20	35	ns
t _W	pulse width	nS input LOW;	5 V		30	15	-	ns
		minimum width;	10 V		20	10	-	ns
		see <u>Figure 4</u>	15 V		16	8	-	ns
		nR input LOW;	5 V		30	15	-	ns
		minimum width;	10 V		20	10	-	ns
		see Figure 4	15 V		16	8		

^[1] The typical values of the propagation delay and transition times are calculated from the extrapolation formulas shown (C_L in pF).

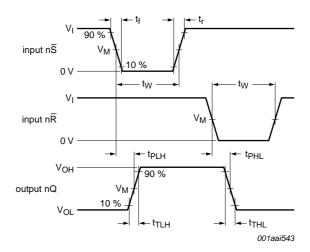
Quad R/S latch with 3-state outputs

Table 8. Dynamic power dissipation P_D

 P_D can be calculated from the formulas shown. $V_{SS} = 0$ V; $t_r = t_f \le 20$ ns; $T_{amb} = 25$ °C.

Symbol	Parameter	V_{DD}	Typical formula for P _D (μW)	where:
P_D	dynamic power	5 V	$P_D = 1300 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$	f_i = input frequency in MHz,
dissipation		10 V	$P_D = 5200 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$	fo = output frequency in MHz,
		15 V	$P_D = 12900 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$	C_L = output load capacitance in pF,
				V_{DD} = supply voltage in V,
				$\Sigma(f_0 \times C_L)$ = sum of the outputs.

12. Waveforms



Measurement points are given in Table 9.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 4. Set (nS) and reset (nR) inputs pulse width and propagation delay to latch output (nQ) and output nQ transition time

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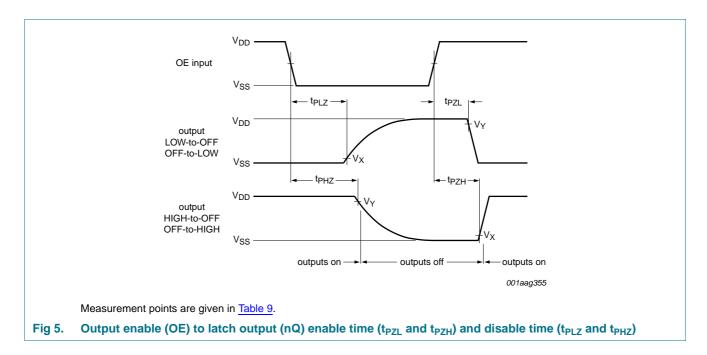
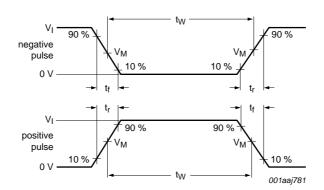


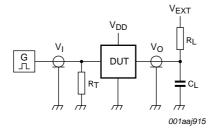
Table 9. Measurement points

Supply voltage	Input		Output					
V_{DD}	V _I V _M		V _M	V _X	V _Y			
5 V to 15 V	V _{DD} or V _{SS}	0.5V _{DD}	0.5V _{DD}	0.1V _{DD}	0.9V _{DD}			

Quad R/S latch with 3-state outputs



a. Input waveform



b. Test circuit

Test and measurement data is given in Table 10.

Definitions test circuit:

DUT = Device Under Test.

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

 C_L = Load capacitance including jig and probe capacitance.

Fig 6. Test circuit for measuring switching times

Table 10. Test data

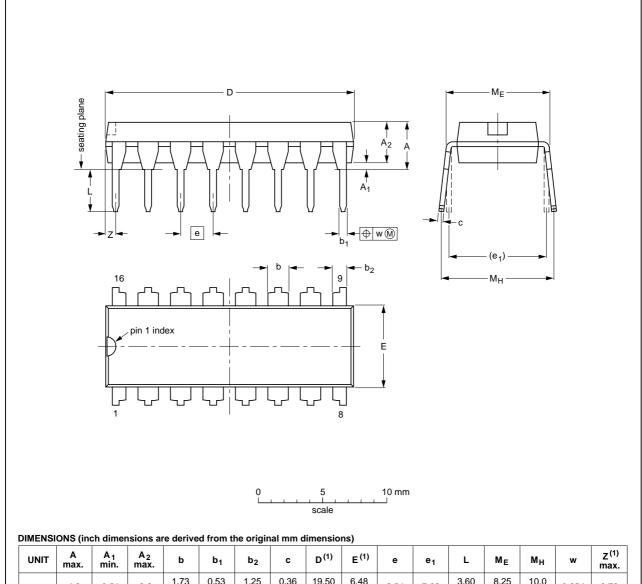
Supply voltage	Input Lo		Load		V _{EXT}			
	V _I	t _r , t _f	CL	R_L	t _{PLH} , t _{PHL}	t_{PLZ} , t_{PZL}	t _{PHZ} , t _{PZH}	
5 V to 15 V	V_{DD}	≤ 20 ns	50 pF	1 kΩ	open	V_{DD}	GND	

Quad R/S latch with 3-state outputs

13. Package outline

DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	b ₂	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.02	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.03

Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT38-4						95-01-14 03-02-13	

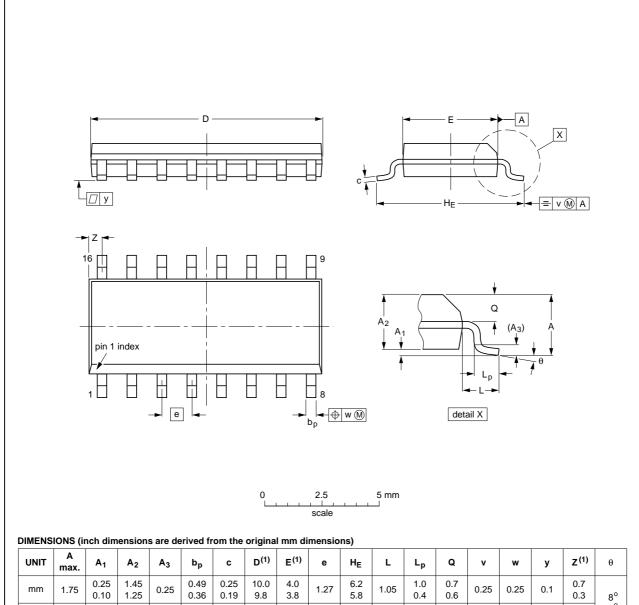
Fig 7. Package outline SOT38-4 (DIP16)

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SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	U	D ⁽¹⁾	E ⁽¹⁾	е	HE	٦	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01	1	0.0100 0.0075	0.39 0.38	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	0°

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

	REFER	EUROPEAN	ISSUE DATE			
IEC	JEDEC	JEITA		PROJECTION	1330E DATE	
076E07	MS-012				99-12-27 03-02-19	
	-	IEC JEDEC		IEC JEDEC JEITA	IEC JEDEC JEITA PROJECTION	

Fig 8. Package outline SOT109-1 (SO16)

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14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
HEF4044B v.10	20111118	Product data sheet	-	HEF4044B v.9
Modifications:	• <u>Table 6</u> : I _{OH}	minimumvalues changed to	maximum	
HEF4044B v.9	20091215	Product data sheet	-	HEF4044B v.8
HEF4044B v.8	20091127	Product data sheet	-	HEF4044B v.7
HEF4044B v.7	20090721	Product data sheet	-	HEF4044B v.6
HEF4044B v.6	20081111	Product data sheet	-	HEF4044B v.5
HEF4044B v.5	20080812	Product data sheet	-	HEF4044B v.4
HEF4044B v.4	20080717	Product data sheet	-	HEF4044B_CNV v.3
HEF4044B_CNV v.3	19950101	Product specification	-	HEF4044B_CNV v.2
HEF4044B_CNV v.2	19950101	Product specification	-	-
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15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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- [1] Please consult the most recently issued document before initiating or completing a design
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